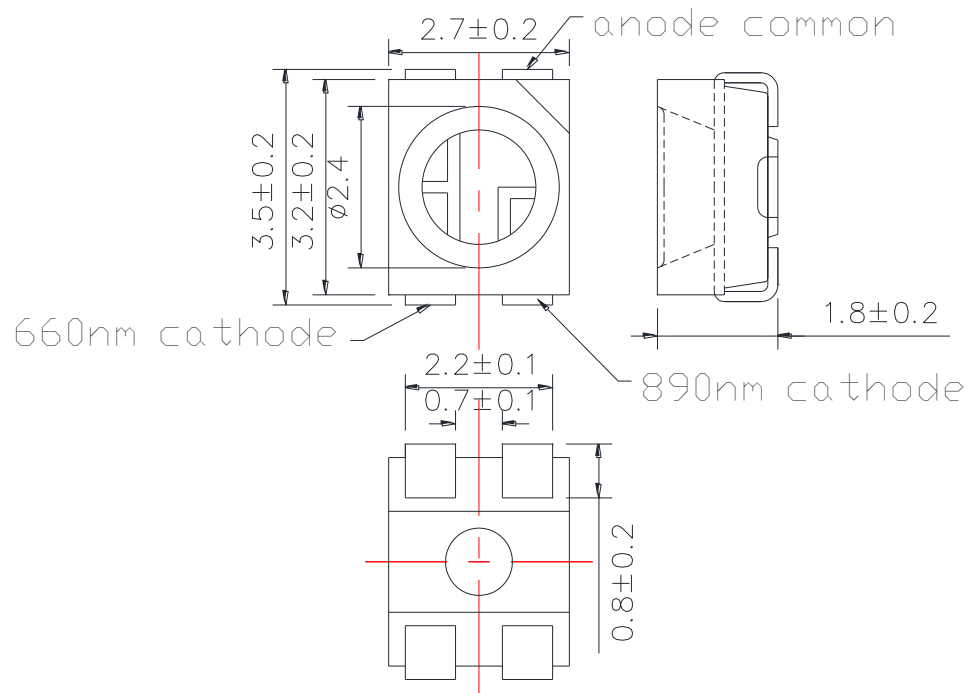


# SMT660D/890

Multi Wavelength LED

## Outline and Internal Circuit



(Unit : mm)

## Feature

- Chip Material : AlGaInP(660nm) , AlGaAs(890nm)
- Chip Dimension : 350um \* 350um(660nm), 400um \* 400um(890nm)
- Number of Chips : 2pcs
- Peak Wavelength : 660/890nm typ.
- Lead Frame Die : Silver Plated on Copper
- Package Resin : PA9T Resin
- Lens : Epoxy Resin

**660nm****Absolute Maximum Ratings (Tc=25°C)**

| Item                  | Symbol | Ratings    | Unit |
|-----------------------|--------|------------|------|
| Power Dissipation     | PD     | 120        | mW   |
| Forward Current       | IF     | 50         | mA   |
| Pulse Forward Current | IFP    | 300        | mA   |
| Reverse Voltage       | VR     | 5          | V    |
| Thermal Resistance    | Rthjs  | 80         | K/W  |
| Junction Temperature  | Tj     | 120        | °C   |
| Operating Temperature | Topr   | -40 ~ +100 | °C   |
| Storage Temperature   | Tstg   | -40 ~ +100 | °C   |
| Soldering Temperature | TSOL   | 250        | °C   |

‡Pulse Forward Current condition : Duty 1% and Pulse Width=10us.

‡Soldering condition : Soldering condition must be completed with 5 seconds at 250°C.

**Optical and Electrical Characteristics (Tc=25°C)**

(\*: 100% testing, \*\*: reference value)

| Parameter            | Symbol | Min | Typ | Max | Unit | Test Condition |
|----------------------|--------|-----|-----|-----|------|----------------|
| Forward Voltage      | VF     |     | 1.9 | 2.3 | V    | IF=20mA*       |
|                      | VFP    |     | 3.5 |     |      | IFP=300mA**    |
| Reverse Current      | IR     |     |     | 10  | uA   | VR=5V*         |
| Total Radiated Power | PO     | 7.7 | 11  |     | mW   | IF=20mA*       |
|                      |        |     | 140 |     |      | IFP=300mA**    |
| Luminous Flux        | Φv     |     | 800 |     | lm   | IF=20mA**      |
| Peak Wavelength      | λp     | 650 |     | 670 | nm   | IF=20mA*       |
| Dominant Wavelength  | λD     |     | 640 |     | nm   | IF=20mA**      |
| Half Width           | Δλ     |     | 16  |     | nm   | IF=20mA**      |
| Rise Time            | tr     |     | 10  |     | ns   | IF=20mA**      |
| Fall Time            | tf     |     | 10  |     | ns   | IF=20mA**      |

‡ Radiated Power is measured by S3584-08.

**890nm****Absolute Maximum Ratings (Tc=25°C)**

| Item                  | Symbol | Ratings    | Unit |
|-----------------------|--------|------------|------|
| Power Dissipation     | PD     | 180        | mW   |
| Forward Current       | IF     | 100        | mA   |
| Pulse Forward Current | IFP    | 500        | mA   |
| Reverse Voltage       | VR     | 5          | V    |
| Thermal Resistance    | Rthjs  | 80         | K/W  |
| Junction Temperature  | Tj     | 120        | °C   |
| Operating Temperature | Topr   | -40 ~ +100 | °C   |
| Storage Temperature   | Tstg   | -40 ~ +100 | °C   |
| Soldering Temperature | TSOL   | 250        | °C   |

‡Pulse Forward Current condition : Duty 1% and Pulse Width=10us.

‡Soldering condition : Soldering condition must be completed with 5 seconds at 250°C.

**Optical and Electrical Characteristics (Tc=25°C)**

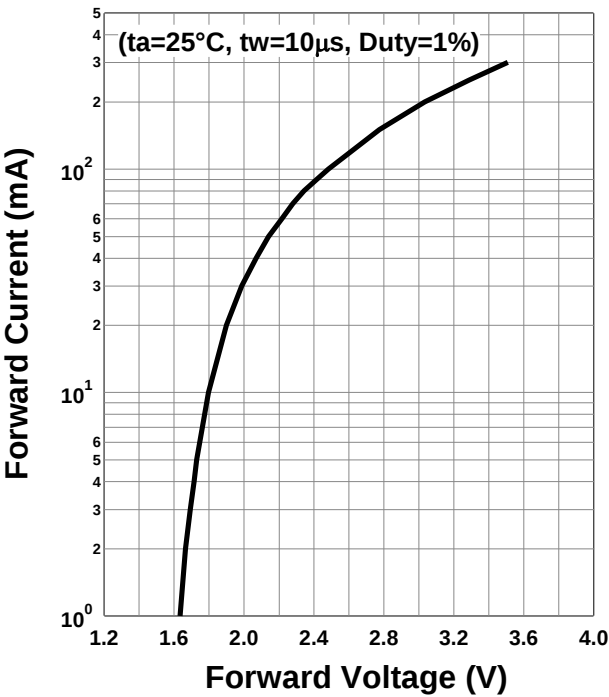
(\*: 100% testing, \*\*: reference value)

| Parameter            | Symbol | Min | Typ | Max | Unit | Test Condition |
|----------------------|--------|-----|-----|-----|------|----------------|
| Forward Voltage      | VF     |     | 1.3 | 1.8 | V    | IF=20mA*       |
|                      | VFP    |     | 2.4 |     |      | IFP=500mA**    |
| Reverse Current      | IR     |     |     | 10  | uA   | VR=5V*         |
| Total Radiated Power | PO     | 3.5 | 5.0 |     | mW   | IF=20mA*       |
|                      |        |     | 120 |     |      | IFP=500mA**    |
| Peak Wavelength      | λp     | 875 |     | 895 | nm   | IF=20mA*       |
| Half Width           | Δλ     |     | 47  |     | nm   | IF=20mA**      |
| Rise Time            | tr     |     | 200 |     | ns   | IF=20mA**      |
| Fall Time            | tf     |     | 300 |     | ns   | IF=20mA**      |

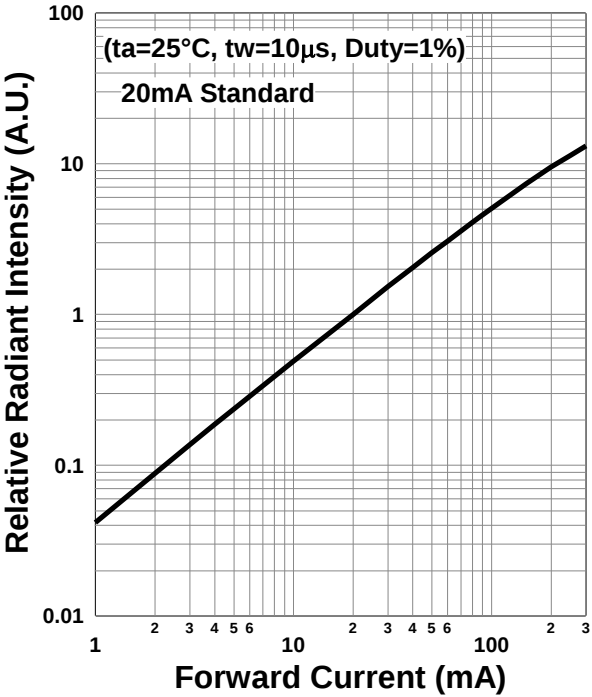
‡ Radiated Power is measured by S3584-08.

Typical Characteristic Curves  
660nm

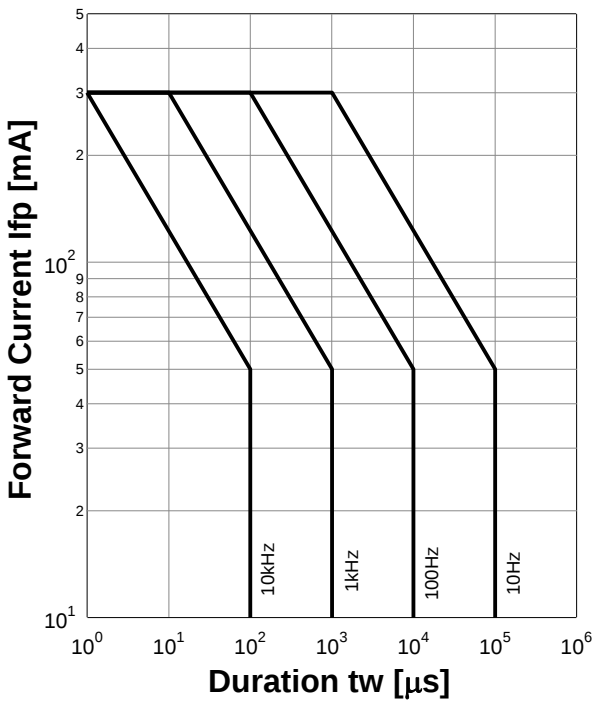
Forward Current - Forward Voltage



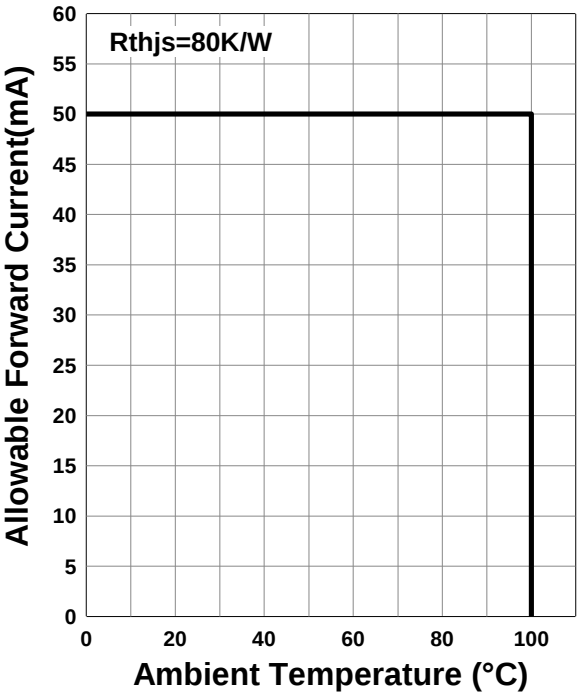
Relative Radiant Intensity -  
Forward Current



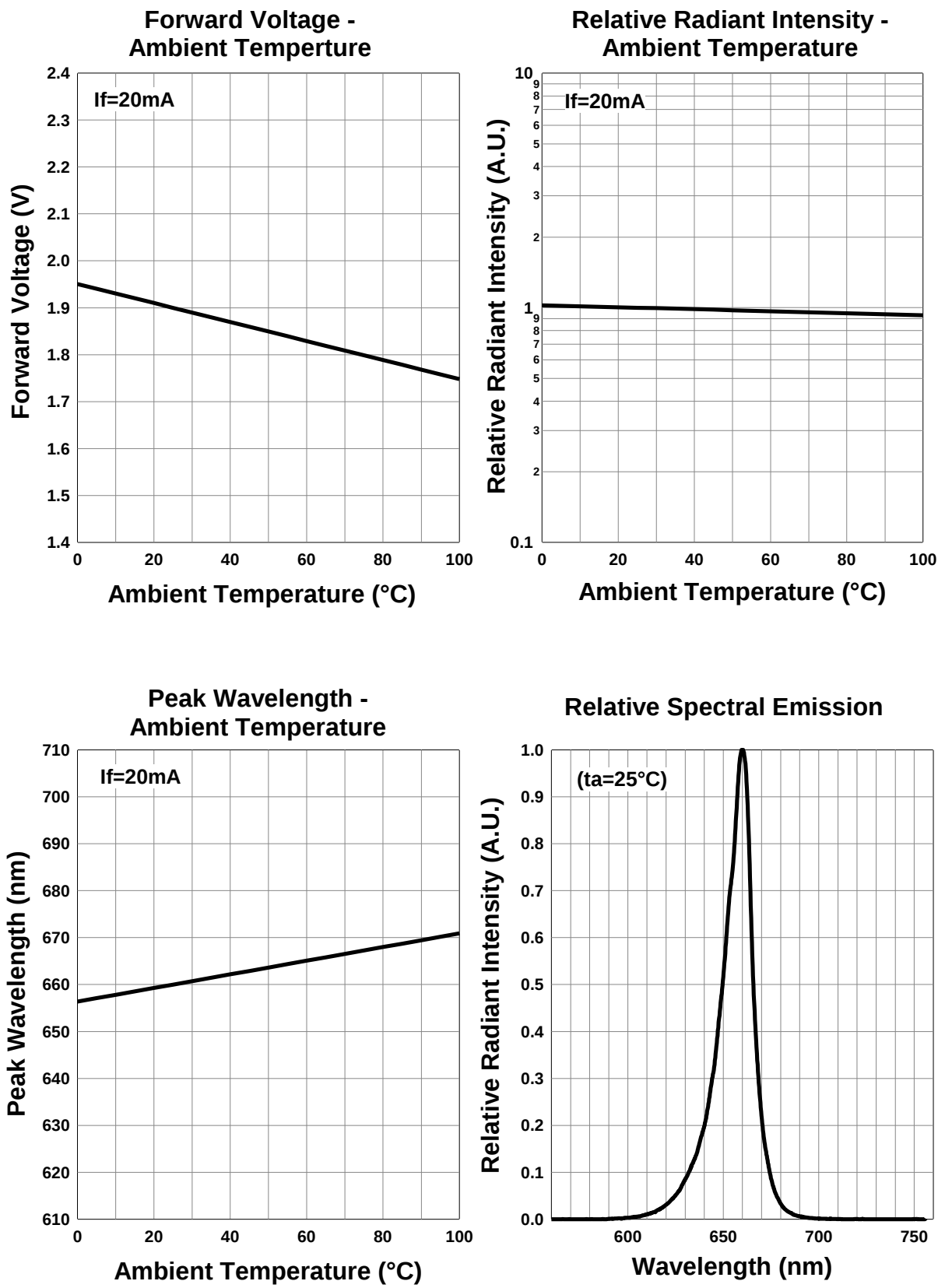
Forward Current - Pulse Duration



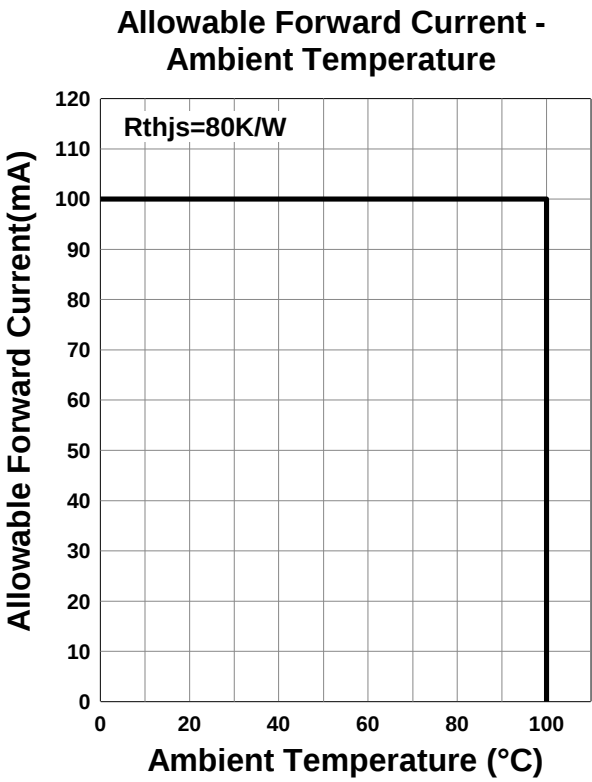
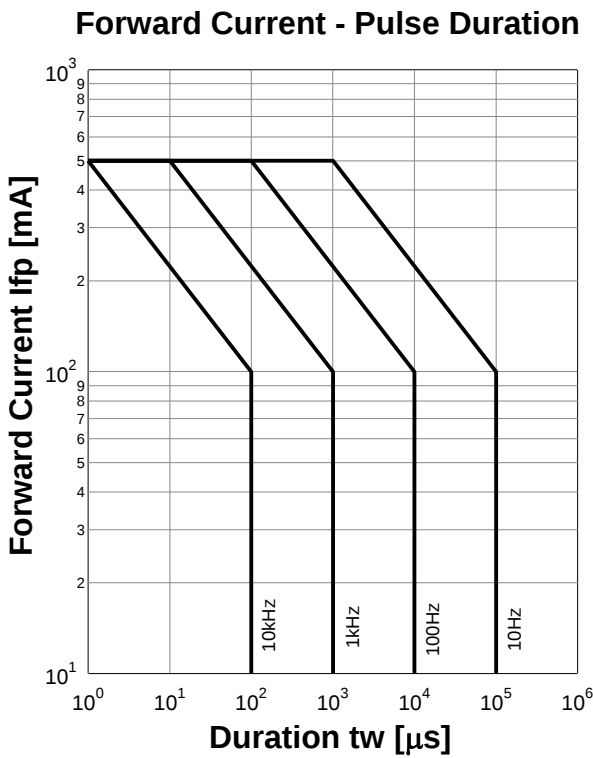
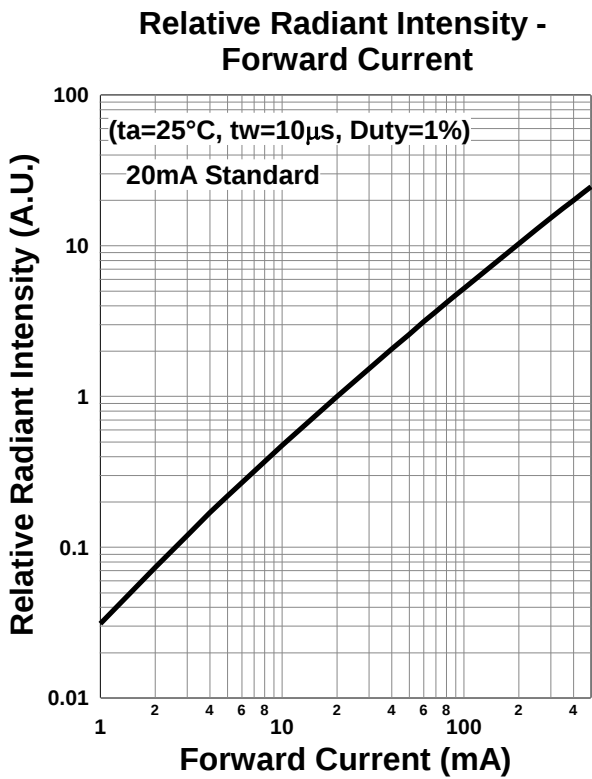
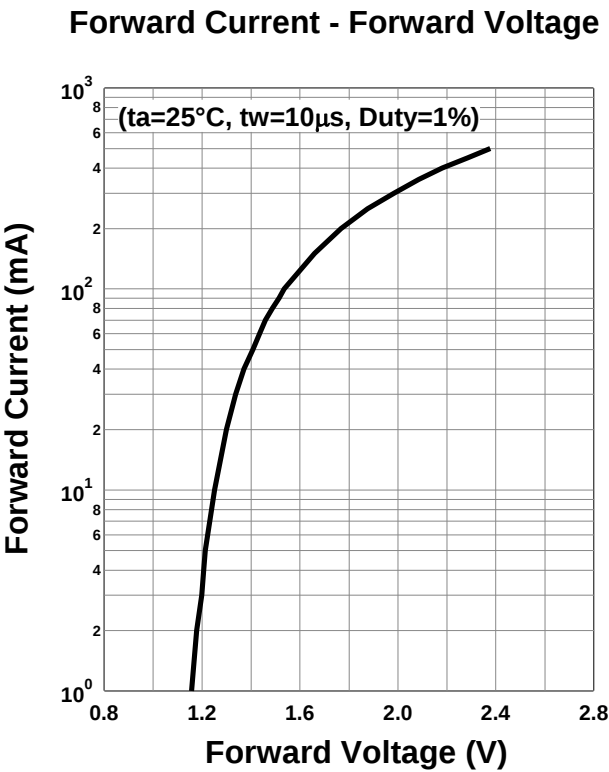
Allowable Forward Current -  
Ambient Temperature



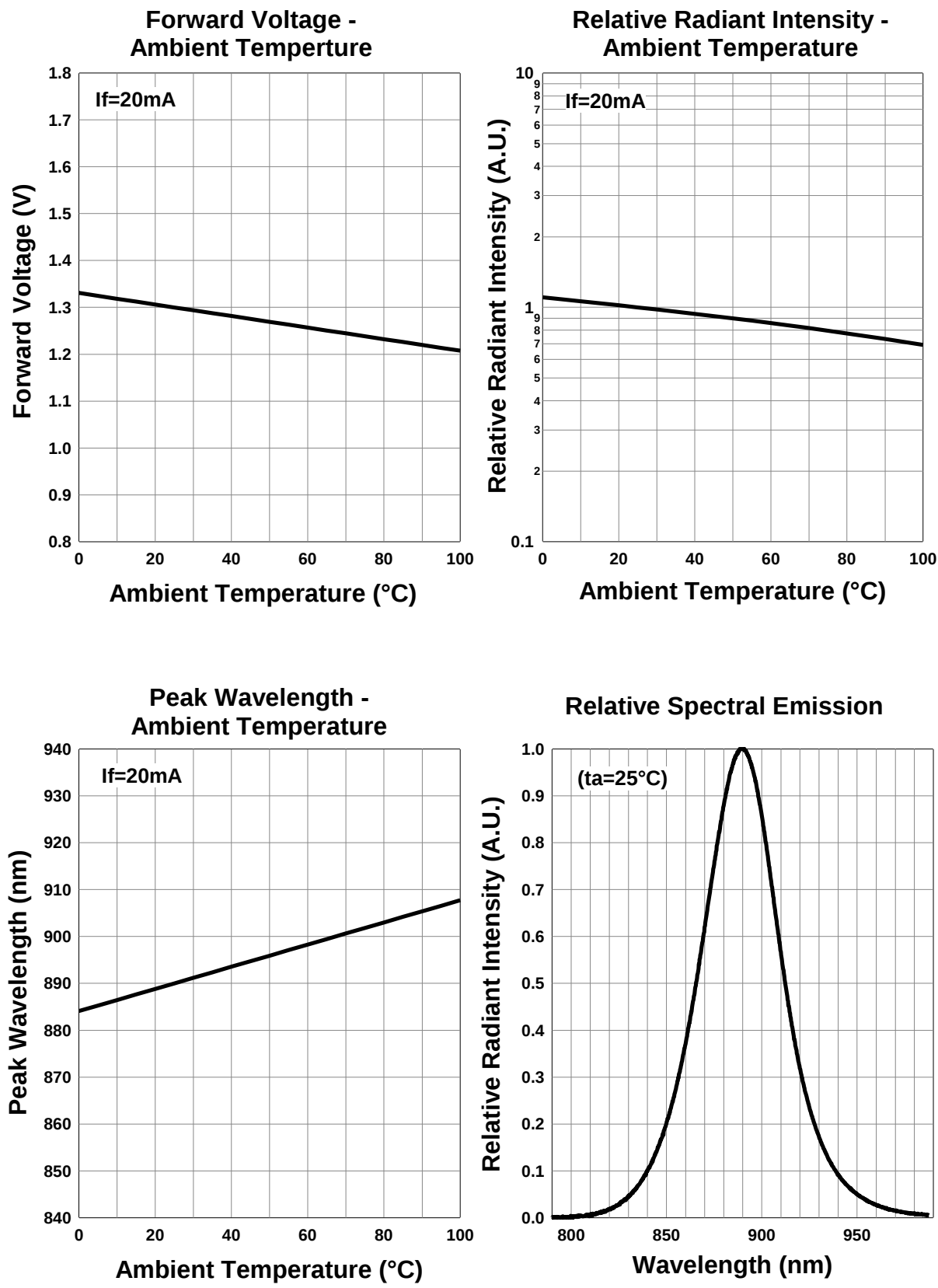
660nm



Typical Characteristic Curves  
890nm



890nm



## **Wrapping**

Moisture barrier bag aluminum laminated film with a desiccant to keep out the moisture absorption during the transportation and storage.

## **SMD LED storage and handling precautions**

### **Storage Conditions before Opening a Moisture-Barrier Aluminum Bag**

- Before opening a moisture-barrier aluminum bag, please store it at <30°C, <60% RH.
- Please note that the maximum shelf life is 12 months under these conditions.

### **Storage Conditions after Opening a Moisture-Barrier Aluminum Bag**

- After opening a moisture-barrier aluminum bag, store the aluminum bag and silica gel in a desiccator.
- After opening the bag, please solder the LEDs within 72 hours in a room with 5 - 30°C, <50%RH.
- Please put any unused, remaining LEDs and silica gel back in the same aluminum bag and then vacuum-seal the bag.
- It is recommended to keep the re-sealed bag in a desiccator at <30%RH.
- The 72-hour- long floor life does not include the time while LEDs are stored in the moisture-barrier aluminum bag. However, we strongly recommend to solder the LEDs as soon as possible after opening the aluminum bag.

### **Notes about Re-sealing a Moisture-Barrier Aluminum Bag**

- When vacuum-sealing an opened aluminum bag, if you find the moisture-indicator of the silica gel has changed to pink from blue (indicating a relative humidity of 30 % or more), please do not use the unused LEDs, the aluminum bag, or the silica gel.

### **Notes about Opening a Re-sealed Moisture-Barrier Aluminum Bag**

- When opening a vacuumed and re-sealed aluminum bag in order to use the remaining LEDs stored in the bag, if you find that the moisture-indicator of the silica has changed to pink, please do not use the LEDs.

**Disclaimer**

Product specifications and data shown in this product catalog are subject to change without notice for the purposes of improving product performance, reliability, design, or otherwise.

Product data and parameters in this catalog are typical values based on reasonably up-to-date measurements.

Product data and parameters may vary by user application and over time.

Products shown in this catalog are intended to be used for general electronic equipment. Products are not guaranteed for applications where product malfunction or failure may cause personal injury or death, including but not limited to life-supporting / saving devices, medical devices, safety devices, airplanes, aerospace equipment, automobiles, traffic control systems, and nuclear reactor control systems.

**The product is manufactured by USHIO Inc. and the spec information is also from USHIO Inc.**

